Supporting Information

Regulating luminescence thermal quenching based on the synergistic effect of energy transfer and energy gap modulation

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Fig. S1 (a) Typical SEM image of YVO₄:Bi³⁺, Eu³⁺solid solution. (b) Mapping diagram of YVO₄:Bi³⁺, Eu³⁺solid solution. (c) The corresponding elemental mapping analysis for the Y, V, O, Bi and Eu elements. (d) EDS spectra of YVO₄:Bi³⁺, Eu³⁺.



Fig. S2 (a) PLE spectra of YVO₄: Eu³⁺ (λ_{em} =596 nm, 621 nm, 621 nm). (b) PL spectra of YVO₄: Eu³⁺ (λ_{ex} =250 nm, 270 nm, 290 nm, 310 nm, 330 nm). (c) CIE chromaticity diagram (λ_{ex} =310 nm). (d) PLE spectra of YVO₄:Bi³⁺, Eu³⁺ (λ_{em} =596 nm, 621 nm). (e) PL spectra of YVO₄:Bi³⁺, Eu³⁺ (λ_{ex} =250 nm, 270 nm, 290 nm, 310 nm, 330 nm). (f) CIE chromaticity diagram (λ_{ex} =310 nm).



Fig. S3 PLE spectra of YVO₄: Eu³⁺, YVO₄:Bi³⁺, Eu³⁺ and YV_{0.25}P_{0.75}O₄:Bi³⁺, Eu³⁺ at λ_{em} =621nm.



Fig. S4 PL spectra of (a) YVO₄: Eu³⁺ (λ_{ex} =320 nm), (b) PL spectra of YVO₄:Bi³⁺, Eu³⁺ (λ_{ex} =310 nm), (c) PL spectra of YV_{0.25}P_{0.75}O₄:Bi³⁺, Eu³⁺ (λ_{ex} =305 nm) at various temperatures. (d) Relative emission intensity of Bi³⁺ at various temperature.



Fig. S5 Thermal quenching activation energy (ΔE) of (a) YVO₄:Bi³⁺, Eu³⁺ and (b) YV_{0.25}P_{0.75}O₄:Bi³⁺, Eu³⁺.